

To our customers,

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## Old Company Name in Catalogs and Other Documents

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On April 1<sup>st</sup>, 2010, NEC Electronics Corporation merged with Renesas Technology Corporation, and Renesas Electronics Corporation took over all the business of both companies. Therefore, although the old company name remains in this document, it is a valid Renesas Electronics document. We appreciate your understanding.

Renesas Electronics website: <http://www.renesas.com>

April 1<sup>st</sup>, 2010  
Renesas Electronics Corporation

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## NPN SILICON GERMANIUM RF TRANSISTOR

# NESG250134

### NPN SiGe RF TRANSISTOR FOR MEDIUM OUTPUT POWER AMPLIFICATION (800 mW) 3-PIN POWER MINIMOLD (34 PKG)

#### FEATURES

- This product is suitable for medium output power (800 mW) amplification  
 $P_O = 29 \text{ dBm TYP. @ } V_{CE} = 3.6 \text{ V, } P_{in} = 15 \text{ dBm, } f = 460 \text{ MHz}$   
 $P_O = 29 \text{ dBm TYP. @ } V_{CE} = 3.6 \text{ V, } P_{in} = 20 \text{ dBm, } f = 900 \text{ MHz}$
- MSG (Maximum Stable Gain) = 23 dB TYP., @  $V_{CE} = 3.6 \text{ V, } I_C = 100 \text{ mA, } f = 460 \text{ MHz}$
- Using UHS2-HV process (SiGe technology),  $V_{CBO}$  (ABSOLUTE MAXIMUM RATINGS) = 20 V
- 3-pin power minimold (34 PKG)

#### ★ ORDERING INFORMATION

Part Number	Order Number	Package	Quantity	Supplying Form
NESG250134	NESG250134-AZ	3-pin power minimold (Pb-Free) <small>Note1, 2</small>	25 pcs (Non reel)	• Magazine case
NESG250134-T1	NESG250134-T1-AZ		1 kpcs/reel	• 12 mm wide embossed taping • Pin 2 (Emitter) face the perforation side of the tape

**Notes 1.** Contains lead in the part except the electrode terminals.

**2.** With regards to terminal solder (the solder contains lead) plated products (conventionally plated), contact your nearby sales office.

**Remark** To order evaluation samples, contact your nearby sales office.

Unit sample quantity is 25 pcs.

#### ABSOLUTE MAXIMUM RATINGS ( $T_A = +25^\circ\text{C}$ )

Parameter	Symbol	Ratings	Unit
Collector to Base Voltage	$V_{CBO}$	20	V
Collector to Emitter Voltage	$V_{CEO}$	9.2	V
Emitter to Base Voltage	$V_{EBO}$	2.8	V
Collector Current	$I_C$	500	mA
★ Total Power Dissipation	$P_{tot}$ <small>Note</small>	1.9	W
Junction Temperature	$T_j$	150	$^\circ\text{C}$
Storage Temperature	$T_{stg}$	-65 to +150	$^\circ\text{C}$

**Note** Mounted on  $34.2 \text{ cm}^2 \times 0.8 \text{ mm}$  (t) glass epoxy PWB

**Caution** Observe precautions when handling because these devices are sensitive to electrostatic discharge.

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★ THERMAL RESISTANCE ( $T_A = +25^\circ\text{C}$ )

Parameter	Symbol	Ratings	Unit
Thermal Resistance from Junction to Ambient <sup>Note</sup>	$R_{thj-a}$	65	$^\circ\text{C/W}$

**Note** Mounted on  $34.2\text{ cm}^2 \times 0.8\text{ mm}$  (t) glass epoxy PWB

RECOMMENDED OPERATING RANGE ( $T_A = +25^\circ\text{C}$ )

Parameter	Symbol	MIN.	TYP.	MAX.	Unit
Collector to Emitter Voltage	$V_{CE}$	—	3.6	4.5	V
Collector Current	$I_C$	—	400	500	mA
Input Power <sup>Note</sup>	$P_{in}$	—	12	17	dBm

**Note** Input power under conditions of  $V_{CE} \leq 4.5\text{ V}$ ,  $f = 460\text{ MHz}$

# ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = +25°C)

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
DC Characteristics						
Collector Cut-off Current	I <sub>CBO</sub>	V <sub>CB</sub> = 5 V, I <sub>E</sub> = 0 mA	–	–	1	μA
Emitter Cut-off Current	I <sub>EBO</sub>	V <sub>EB</sub> = 0.5 V, I <sub>C</sub> = 0 mA	–	–	1	μA
DC Current Gain	h <sub>FE</sub> <sup>Note 1</sup>	V <sub>CE</sub> = 3 V, I <sub>C</sub> = 100 mA	80	120	180	–
RF Characteristics						
Gain Bandwidth Product	f <sub>T</sub>	V <sub>CE</sub> = 3.6 V, I <sub>C</sub> = 100 mA, f = 460 MHz	–	10	–	GHz
Insertion Power Gain	S <sub>21e</sub>   <sup>2</sup>	V <sub>CE</sub> = 3.6 V, I <sub>C</sub> = 100 mA, f = 460 MHz	–	19	–	dB
Maximum Satble Gain	MSG <sup>Note 2</sup>	V <sub>CE</sub> = 3.6 V, I <sub>C</sub> = 100 mA, f = 460 MHz	–	23	–	dB
Linner gain (1)	G <sub>L</sub>	V <sub>CE</sub> = 3.6 V, I <sub>C (set)</sub> = 30 mA (RF OFF), f = 460 MHz, P <sub>in</sub> = 0 dBm	16	19	–	dB
Linner gain (2)	G <sub>L</sub>	V <sub>CE</sub> = 3.6 V, I <sub>C (set)</sub> = 30 mA (RF OFF), f = 900 MHz, P <sub>in</sub> = 0 dBm	–	16	–	dB
Output Power (1)	P <sub>O</sub>	V <sub>CE</sub> = 3.6 V, I <sub>C (set)</sub> = 30 mA (RF OFF), f = 460 MHz, P <sub>in</sub> = 15 dBm	27	29	–	dBm
Output Power (2)	P <sub>O</sub>	V <sub>CE</sub> = 3.6 V, I <sub>C (set)</sub> = 30 mA (RF OFF), f = 900 MHz, P <sub>in</sub> = 20 dBm	–	29	–	dBm
Collector Efficiency (1)	η <sub>c</sub>	V <sub>CE</sub> = 3.6 V, I <sub>C (set)</sub> = 30 mA (RF OFF), f = 460 MHz, P <sub>in</sub> = 15 dBm	–	60	–	%
Collector Efficiency (2)	η <sub>c</sub>	V <sub>CE</sub> = 3.6 V, I <sub>C (set)</sub> = 30 mA (RF OFF), f = 900 MHz, P <sub>in</sub> = 20 dBm	–	60	–	%

**Notes 1.** Pulse measurement: PW ≤ 350 μs, Duty Cycle ≤ 2%

$$2. \text{MSG} = \left| \frac{S_{21}}{S_{12}} \right|$$

## h<sub>FE</sub> CLASSIFICATION

Rank	FB
Marking	SN
h <sub>FE</sub> Value	80 to 180

## ★ S-PARAMETERS

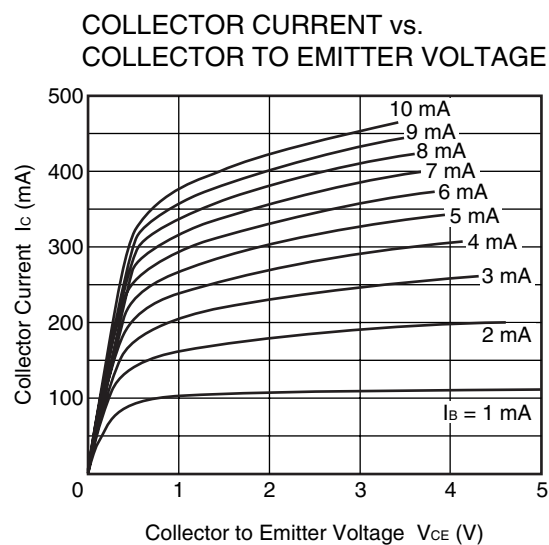
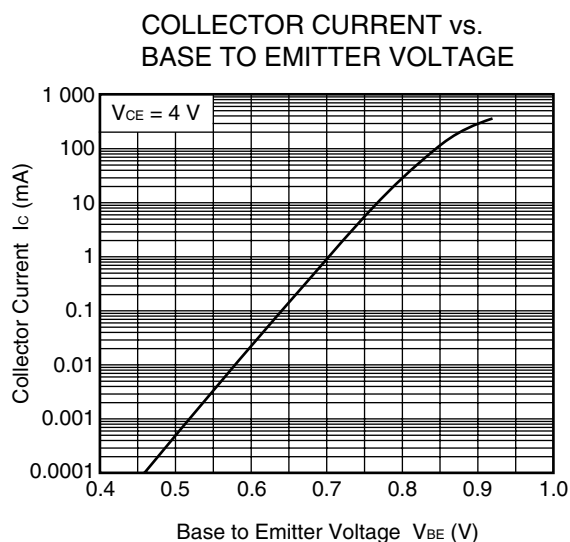
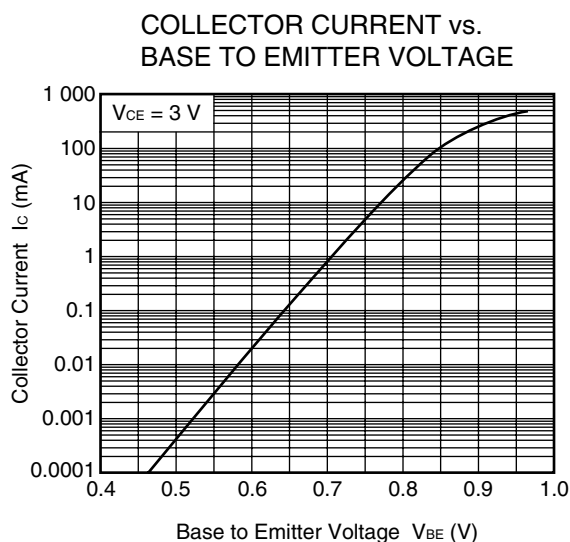
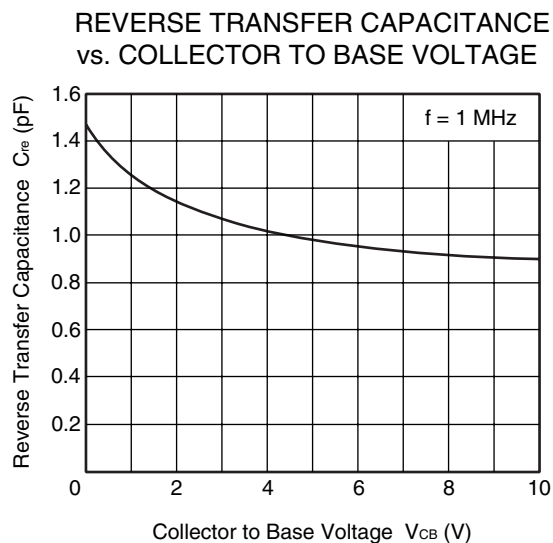
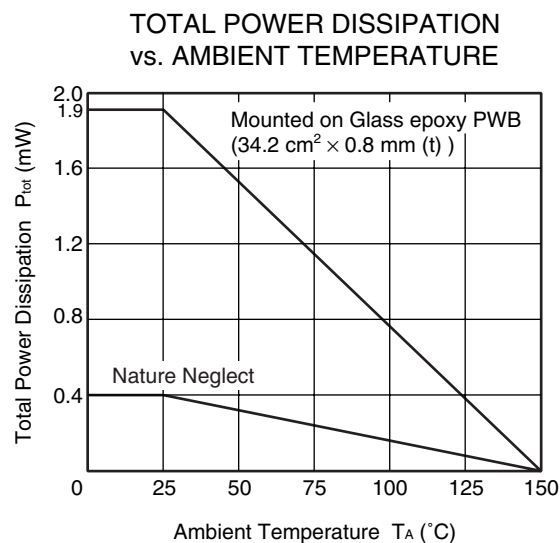
S-parameters/Noise parameters are provided on the NEC Compound Semiconductor Devices Web site in a form (S2P) that enables direct import to a microwave circuit simulator without keyboard input.

Click here to download S-parameters.

[RF and Microwave] → [Device Parameters]

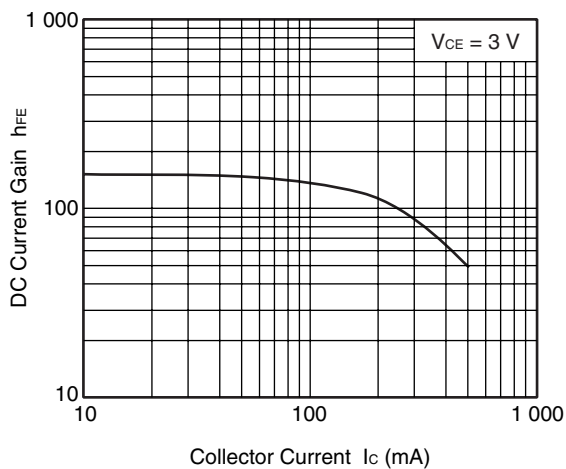
URL <http://www.ncsd.necel.com/>

★ TYPICAL CHARACTERISTICS ( $T_A = +25^\circ\text{C}$ , unless otherwise specified)

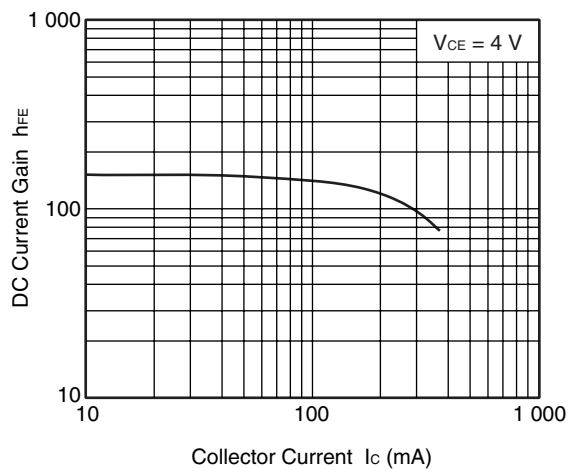


**Remark** The graphs indicate nominal characteristics.

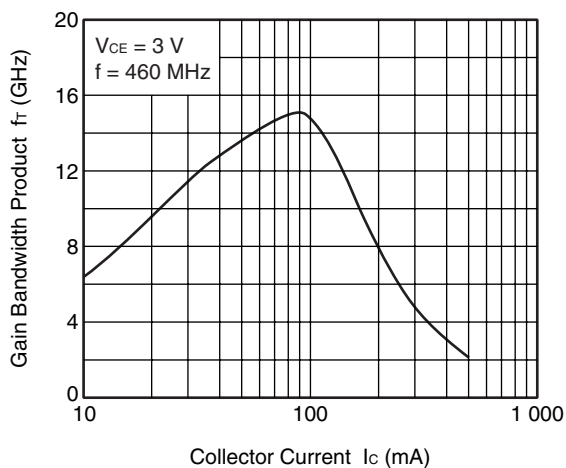
DC CURRENT GAIN vs.  
COLLECTOR CURRENT



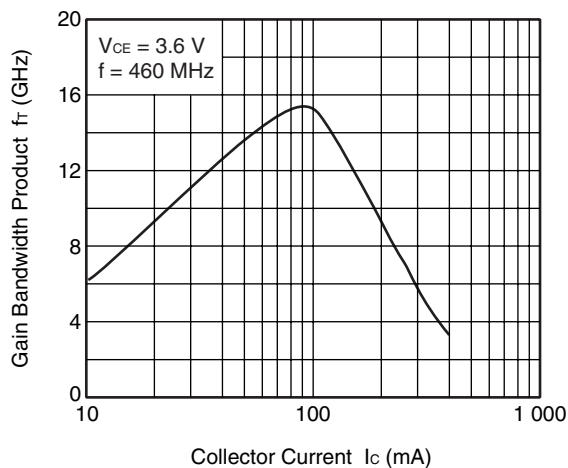
DC CURRENT GAIN vs.  
COLLECTOR CURRENT



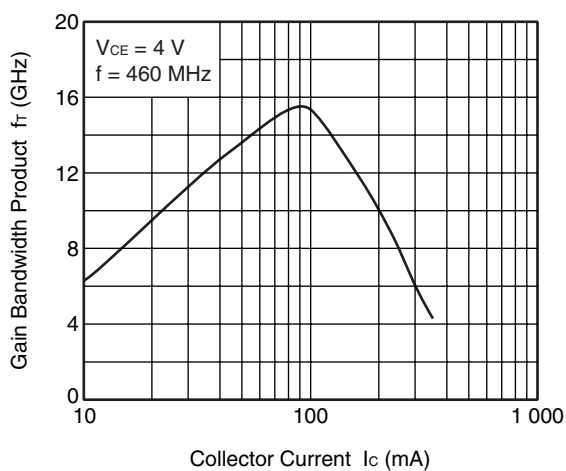
GAIN BANDWIDTH PRODUCT  
vs. COLLECTOR CURRENT



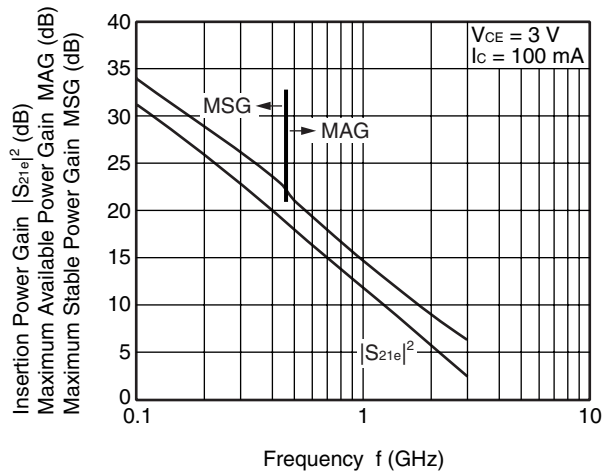
GAIN BANDWIDTH PRODUCT  
vs. COLLECTOR CURRENT



GAIN BANDWIDTH PRODUCT  
vs. COLLECTOR CURRENT

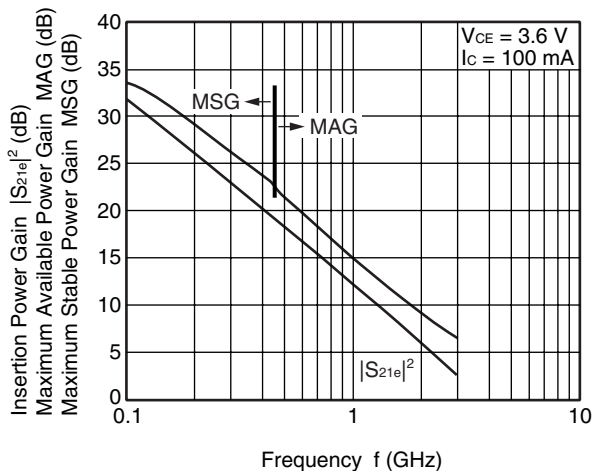


INSERTION POWER GAIN,  
MAG, MSG vs. FREQUENCY

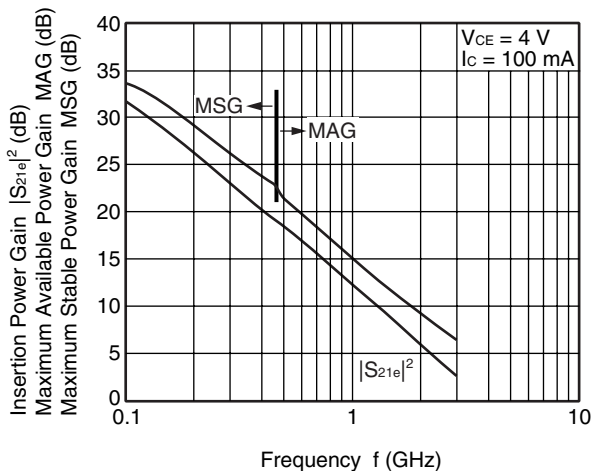


**Remark** The graphs indicate nominal characteristics.

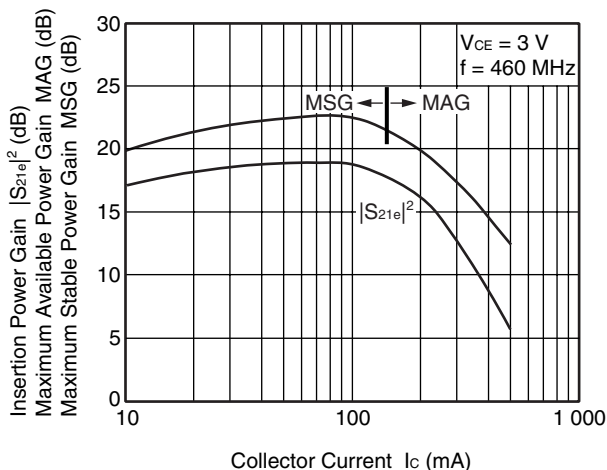
INSERTION POWER GAIN, MAG, MSG vs. FREQUENCY



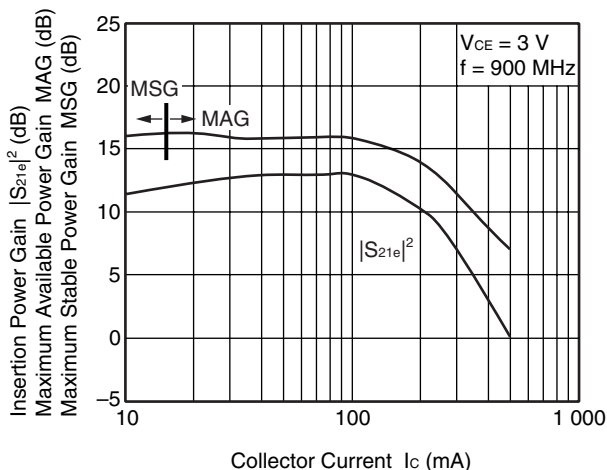
INSERTION POWER GAIN, MAG, MSG vs. FREQUENCY



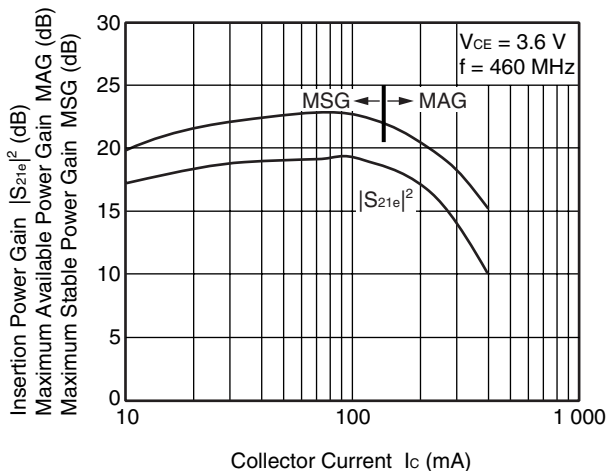
INSERTION POWER GAIN, MAG, MSG vs. COLLECTOR CURRENT



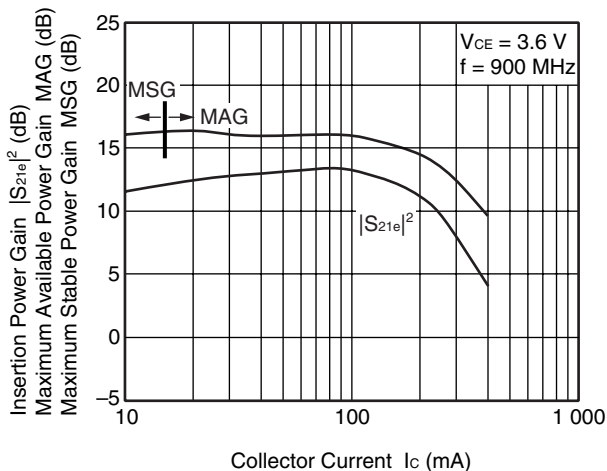
INSERTION POWER GAIN, MAG, MSG vs. COLLECTOR CURRENT



INSERTION POWER GAIN, MAG, MSG vs. COLLECTOR CURRENT

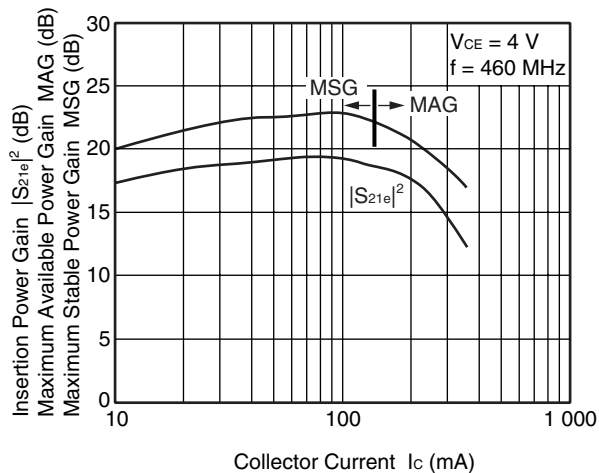


INSERTION POWER GAIN, MAG, MSG vs. COLLECTOR CURRENT

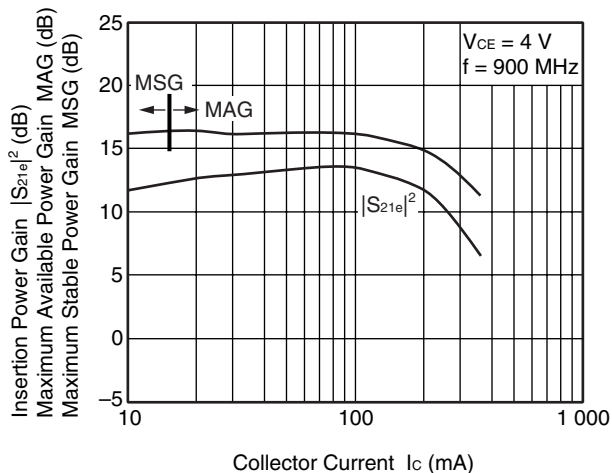


**Remark** The graphs indicate nominal characteristics.

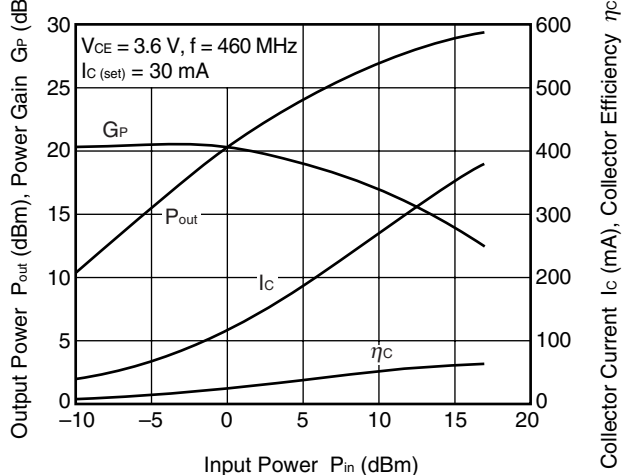
INSERTION POWER GAIN, MAG, MSG  
vs. COLLECTOR CURRENT



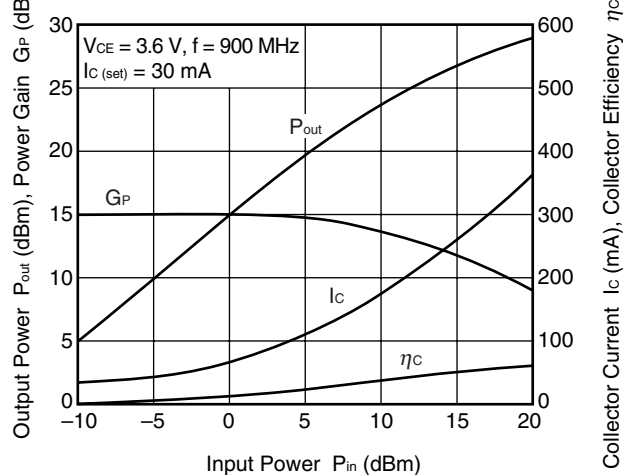
INSERTION POWER GAIN, MAG, MSG  
vs. COLLECTOR CURRENT



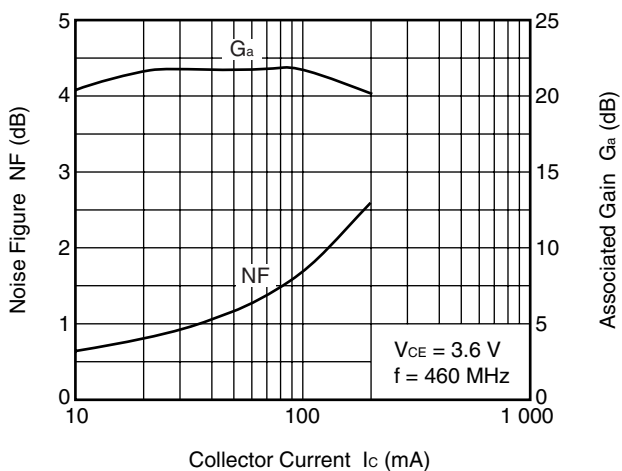
OUTPUT POWER, POWER GAIN,  
COLLECTOR CURRENT, COLLECTOR  
EFFICIENCY vs. INPUT POWER



OUTPUT POWER, POWER GAIN,  
COLLECTOR CURRENT, COLLECTOR  
EFFICIENCY vs. INPUT POWER

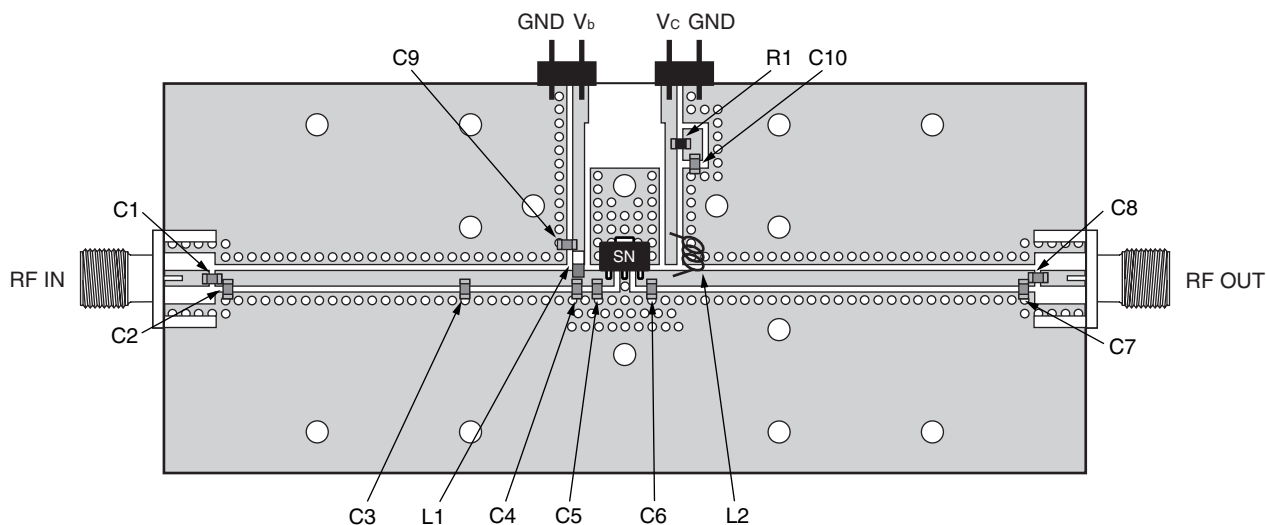


NOISE FIGURE, ASSOCIATED GAIN  
vs. COLLECTOR CURRENT



**Remark** The graphs indicate nominal characteristics.

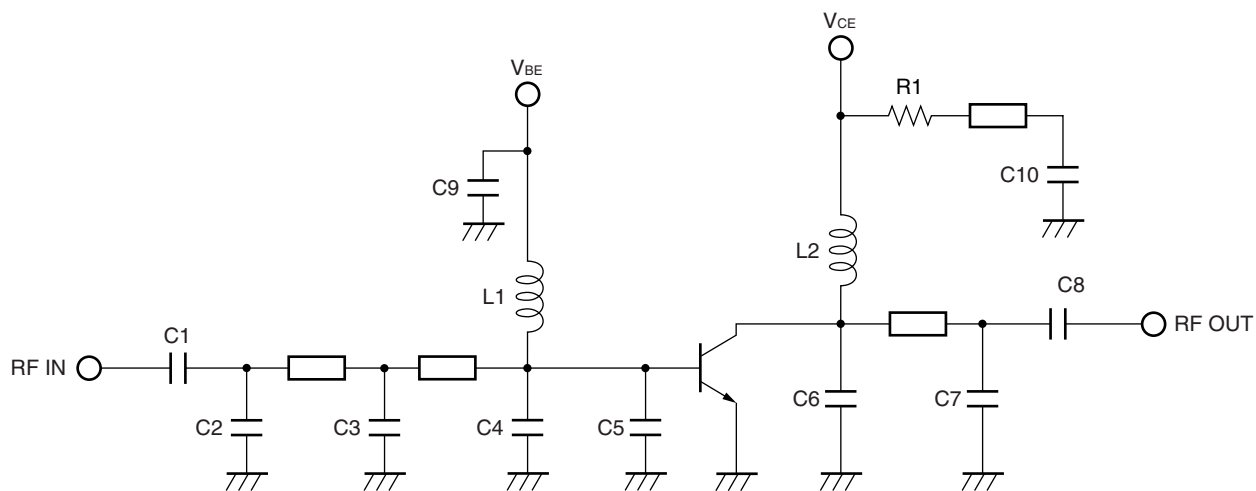
**PA EVALUATION BOARD (f = 460 MHz)**



**Notes**

1. 38 × 90 mm, t = 0.8 mm double sided copper clad glass epoxy PWB.
2. Back side: GND pattern
3. Solder gold plated on pattern
4. ○○: Through holes

**PA EVALUATION CIRCUIT (f = 460 MHz)**



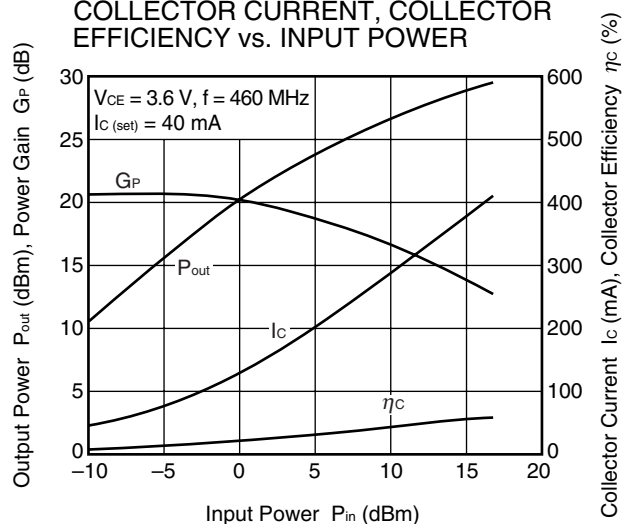
The application circuits and their parameters are for reference only and are not intended for use in actual design-ins.

# COMPONENT LIST

	Value	Maker
C1	30 pF	Murata
C2	6 pF	Murata
C3, C4	7 pF	Murata
C5	3 pF	Murata
C6	0.5 pF	Murata
C7	5 pF	Murata
C8	10 pF	Murata
C9, C10	100 nF	Murata
L1	100 nH	Toko
L2	3 nH	Toko
R1	30 $\Omega$	SSM

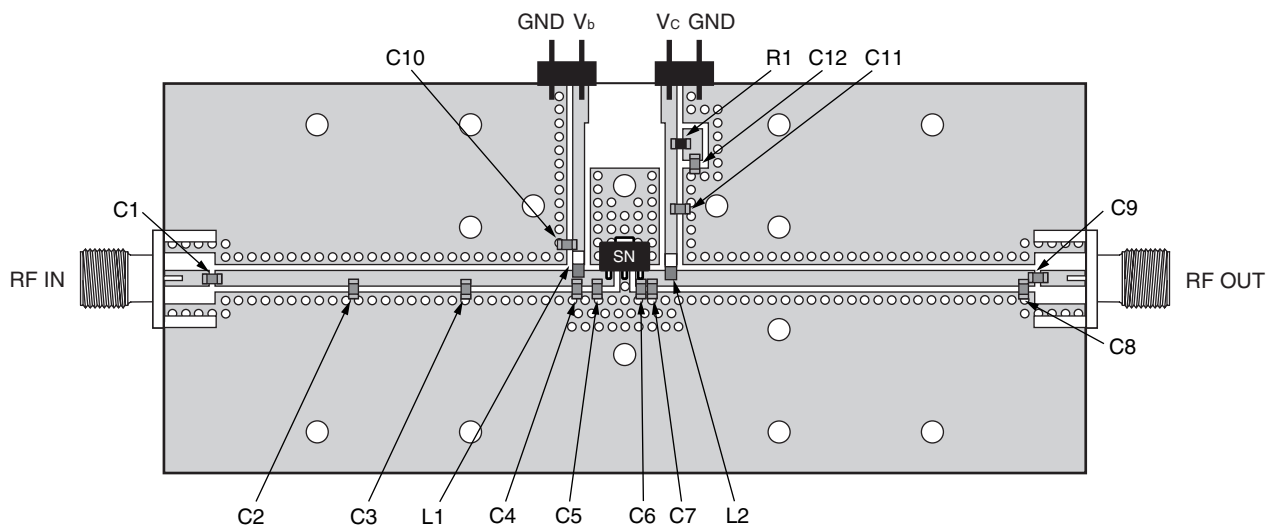
## PA EVALUATION CIRCUIT TYPICAL CHARACTERISTICS

OUTPUT POWER, POWER GAIN,  
COLLECTOR CURRENT, COLLECTOR  
EFFICIENCY vs. INPUT POWER



**Remark** The graph indicates nominal characteristics.

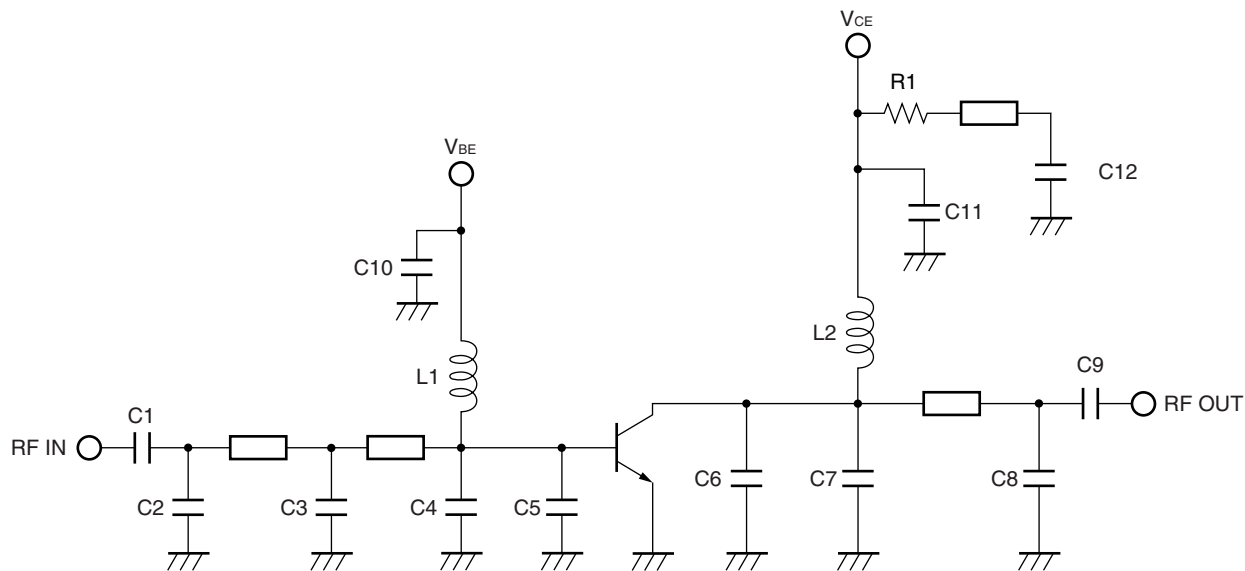
# **DISTORTION EVALUATION BOARD (f = 460 MHz)**



## **Notes**

1. 38 × 90 mm, t = 0.8 mm, double sided copper clad glass epoxy PWB.
2. Back side: GND pattern
3. Solder gold plated on pattern
4. ○○: Through holes

# **DISTORTION EVALUATION CIRCUIT (f = 460 MHz)**



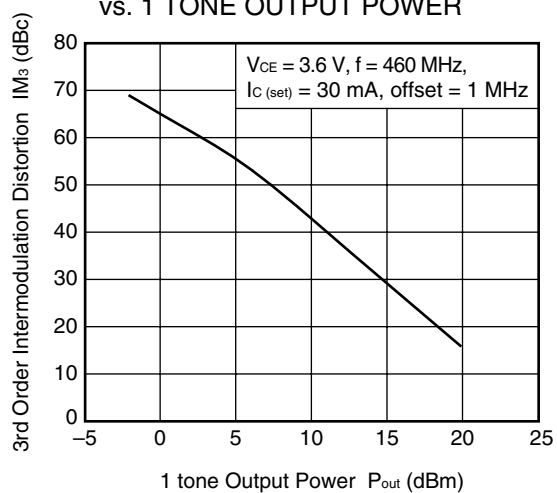
The application circuits and their parameters are for reference only and are not intended for use in actual design-ins.

# COMPONENT LIST

	Value	Maker
C1	47 pF	Murata
C2	12 pF	Murata
C3, C4	7 pF	Murata
C5	3 pF	Murata
C6	6 pF	Murata
C7	0.5 pF	Murata
C8	5 pF	Murata
C9	51 pF	Murata
C10, C12	100 nF	Murata
C11	1 $\mu$ F	Murata
L1	100 nH	Toko
L2	15 nH	Toko
R1	30 $\Omega$	SSM

## DISTORTION EVALUATION CIRCUIT TYPICAL CHARACTERISTICS

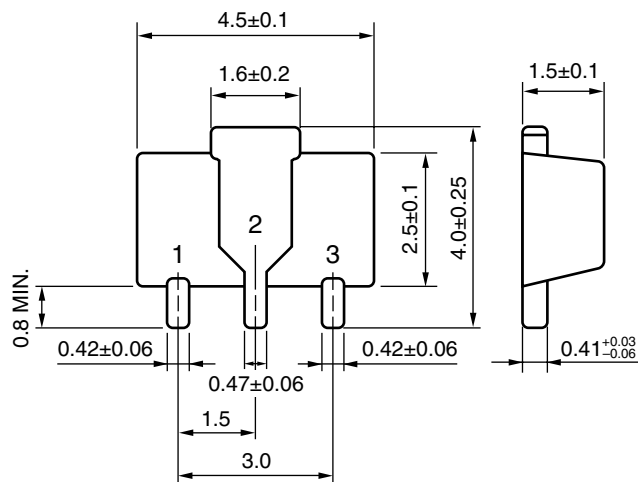
### 3RD ORDER INTERMODULATION DISTORTION vs. 1 TONE OUTPUT POWER



**Remark** The graph indicates nominal characteristics.

# PACKAGE DIMENSIONS

## 3-PIN POWER MINIMOLD (34 PKG) (UNIT: mm)



## PIN CONNECTIONS

1. Collector
2. Emitter
3. Base

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